NSN 5962-01-381-8096

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Body Length: 0.440 inches **Body Width:** Between 0.045 inches and 0.085 inches **Body Height:** Between 0.045 inches and 0.085 inches **Maximum Power Dissipation Rating:** 100.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Bipolar and monolithic and schottky **Inclosure Material:** Ceramic **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Case Outline Source And Designator:** F-5 mil-m-38510 **Current Rating Per Characteristic:** 130.00 milliamperes reverse current, dc minor **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 35.00 nanoseconds propagation delay time, high to low level output and 20.00 nanoseconds propagation delay time, low to high level output Memory Device Type: Prom **Test Data Document:** 81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification

format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

16 flat leads

Specification Data:

81349-mil-m-38510/203 government specification

Shelf Life:

NI/o

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Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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